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 Mechatronics Engineering i

(2) $V_s = 20V$
 $V_z = ?$
 max current = $50mA = 1s$
 $P_z = 5W = 500 \times 10^{-3}$

(i) $I_s = \frac{V_s - V_z}{R_z} = \frac{20 - V_z}{500 \times 10^{-3}} = 10V$

so $V_z = 10V$
 $R_s = \frac{V_s - V_z}{I_z} = \frac{20 - 10}{500 \times 10^{-3}} = \frac{10}{500 \times 10^{-3}} = 20$

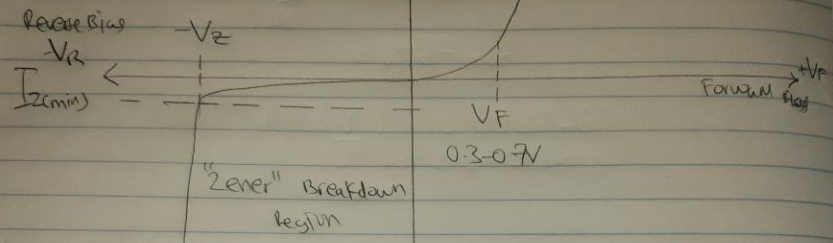
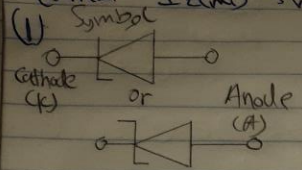
$R_s = 20 \Omega$

(ii) $I_z = I_s - I_L$ & $I_L = \frac{V_z}{R_L} = \frac{10}{500} = 0.02A$
 $= 20mA$

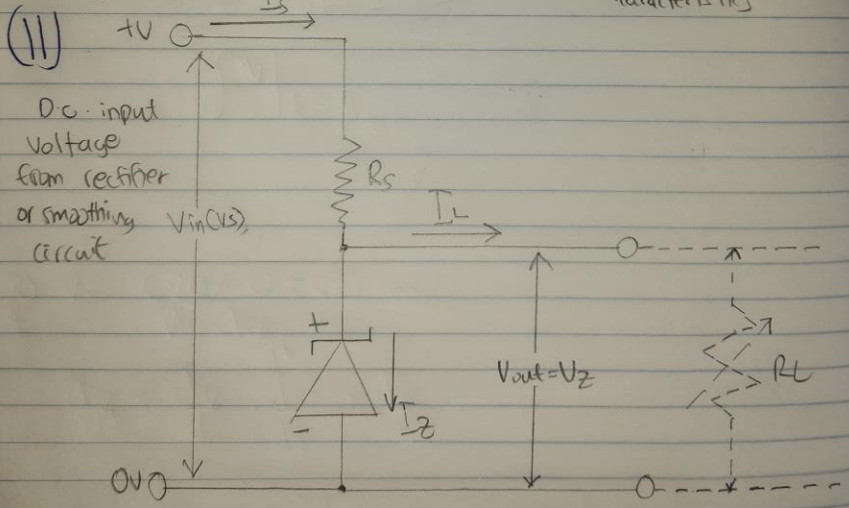
so $I_z = (500 - 20) mA = 480mA$

(1) The zener diode is used in its "reverse bias" or reverse breakdown mode, i.e. the diode's anode is connect to the negative supply. The zener diode has a region in its reverse bias characteristics of almost a constant negative voltage, regardless of the value of the current flowing through the diode & remains nearly constant even with large changes in current as long as the zener diode current remains between the breakdown

current $I_{Z(m)}$ is max current rating I_Z (mA).



Reverse Bias $-V_Z$
 $I_{Z(m)}$
 Constant Zener Voltage I_S
 Reverse current $-I_Z$
 Zener Diode I-V Characteristics



Zener Diode Regulator